ABSOLUTE MAXIMUM RATINGS

(Voltage Referenced to V-)

V+	
GND	
VL(GND - 0.3V) to (V+ + 0.3V)	
Digital Inputs V _S , V _D (Note 1)(V 2V) to (V+ + 2V) or 30mÁ	
(whichever occurs first))
Continuous Current (any terminal)	
Peak Current, S or D (pulsed at 1ms, 10% duty cycle max) .100mA	

Continuous Power Dissipation ($T_A = +70^{\circ}C$)
6-Pin Narrow SO (derate 8.70mW/°C above +70°C)696mW
16-Pin PDIP (derate 10.53mW/°C above +70°C)842mW
16-Pin Thin QFN (derate 33.3mW/°C above +70°C)2667mW
Operating Temperature Ranges
DG444C/DG445C0°C to +70°C
DG444D, E/DG445D, E40°C to +85°C
Storage Temperature Range65°C to +150°C
Lead Temperature (soldering, 10s)+300°C

Note 1: Signals on S, D, or IN exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = 15V, V- = -15V, VL = 5V, GND = 0, VINH = 2.4V, VINL = 0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS	
SWITCH								
Analog Signal Range	VANALOG	(Note 3)		-15		+15	V	
Drain-Source	Rds(on)	V+ = 13.5V, V- = -13.5V,	$T_A = +25^{\circ}C$		50	85	- Ω	
On-Resistance	103(014)	$V_D = \pm 8.5 V$, $I_S = -10 mA$	$T_A = T_{MIN}$ to T_{MAX}			100		
On-Resistance Match	$\Delta R_{DS(ON)}$	$V_{\rm D} = \pm 10 V_{\rm r}$	$T_A = +25^{\circ}C$			4		
Between Channels (Note 4)	ANDS(ON)	$I_{S} = -10 mA$	$T_A = T_{MIN}$ to T_{MAX}			5	Ω	
On-Resistance Flatness (Note 4) R	R _{FLAT(ON)}	V _D = ±5V, I _S = -10mA	$T_A = +25^{\circ}C$			9	Ω	
			$T_A = T_{MIN}$ to T_{MAX}			15		
Source Leakage Current (Note 5)	$\label{eq:scalar} \begin{array}{l} V+=16.5V,V-=-16.5V,\\ V_D=\pm 15.5V,\\ V_S=\mp 15.5V \end{array}$		$T_A = +25^{\circ}C$	-0.50	+0.01	+0.50	nA	
		$T_A = T_{MIN}$ to T_{MAX}	-5		+5			
Drain Off-Leakage Current		V+ = 16.5V, V- = -16.5V,	$T_A = +25^{\circ}C$	-0.50	+0.01	+0.50	n۸	
(Note 5)	ID(OFF)	$V_{D} = \pm 15.5V,$ $V_{S} = \mp 15.5V$	$T_A = T_{MIN}$ to T_{MAX}	-5		+5	– nA	
Drain On-Leakage Current	ID(ON)	$V_{+} = 16.5V, V_{-} = -16.5V,$	$T_A = +25^{\circ}C$	-0.50	+0.08	+0.50		
(Note 5)	or I _{S(ON)}	$V_D = \pm 15.5V,$ $V_S = \pm 15.5V$	$T_A = T_{MIN}$ to T_{MAX}	-10		+10	nA	
INPUT								
Input Current with Input Voltage High	I _{INH}	$V_{IN} = 2.4V$, all others = 0.8V		-0.5	-0.00001	+0.5	μA	
Input Current with Input Voltage Low	I _{INL}	$V_{IN} = 0.8V$, all others = 2.4V		-0.5	-0.00001	+0.5	μA	

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

(V + = 15V, V - = -15V, VL = 5V, GND = 0, VINH = 2.4V, VINL = 0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS			TYP (Note 2)	МАХ	UNITS	
SWITCH								
Power-Supply Range	V+, V-			±4.5		±20.0	V	
Positive Supply Current	+	All channels on or off, V + = 16.5V, V- = -16.5V, V _{IN} = 0V	$T_A = +25^{\circ}C$	-1	-0.001	+1		
Tositive Supply Current		or 5V	$T_A = T_{MIN}$ to T_{MAX}	-5		+5	μA	
Negative Supply Current	-	All channels on or off, V + = 16.5V, V- = -16.5V, V _{IN} = 0V	$T_A = +25^{\circ}C$	-1	-0.0001	+1		
Negative Supply Current	1-	or 5V	$T_A = T_{MIN}$ to T_{MAX}	-5		+5	- μΑ	
Logic Supply Current	l.	All channels on or off, V + = 16.5V, V- = -16.5V, VIN = 0V	$T_A = +25^{\circ}C$	-1	-0.001	+1		
Logic Supply Current		or 5V	$T_A = T_{MIN}$ to T_{MAX}	-5		+5	μA	
		All channels on or off, $V_{+} =$	$T_A = +25^{\circ}C$	-1	-0.0001	+1		
Ground Current	IGND	16.5V, V- = -16.5V, V _{IN} = 0V or 5V	TA = TMIN to TMAX	-5		+5	μA	
INPUT								
Turn-On Time	ton	$V_S = \pm 10V$, Figure 2	$T_A = +25^{\circ}C$		150	250	ns	
T 0""T		DG444, $V_S = \pm 10V$, Figure 2	$T_A = +25^{\circ}C$		90	120	ns	
Turn-Off Time	toff	DG445, $V_S = \pm 10V$, Figure 2	$T_A = +25^{\circ}C$		110	170	ns	
Charge Injection (Note 3)	Q	$C_L = 1nF$, $V_{GEN} = 0$, $R_{GEN} = 0\Omega$, Figure 3	$T_A = +25^{\circ}C$		5	10	рС	
Off-Isolation Rejection Ratio (Note 6)	OIRR	$R_L = 50\Omega$, $C_L = 5pF$, f = 1MHz, Figure 4	$T_A = +25^{\circ}C$		60		dB	
Crosstalk (Note 7)		$R_L -50\Omega$, $C_L = 5pF$, f = 1MHz, Figure 5	$T_A = +25^{\circ}C$		100		dB	
Source Off-Capacitance	C _{S(OFF)}	f = 1MHz, Figure 6	$T_A = +25^{\circ}C$		4		pF	
Drain Off-Capacitance	CD(OFF)	f = 1MHz, Figure 6	$T_A = +25^{\circ}C$		4		pF	
Source On-Capacitance	Cs(ON)	f = 1MHz, Figure 7	$T_A = +25^{\circ}C$		16		pF	
Drain On-Capacitance	C _{D(ON)}	f = 1MHz, Figure 7	$T_A = +25^{\circ}C$		16		рF	

ELECTRICAL CHARACTERISTICS—Single Supply

 $(V + = 12V, V - = 0, V_L = 5V, GND = 0, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
SWITCH							
Analog Signal Range	Vanalog	(Note 3)		0		12	V
Drain-Source	Destaut	V+ = 10.8V; VL = 5.25V;	$T_A = +25^{\circ}C$		100	160	Ω
On-Resistance	R _{DS(ON)}	$V_D = 3V, 8V; I_S = -10mA$	$T_A = T_{MIN}$ to T_{MAX}			200	
SUPPLY							1
Power-Supply Range	V+, V-			10.8		24.0	V
Dewer Current	+	All channels on or off,	$T_A = +25^{\circ}C$	-1	+0.001	+1	
Power-Supply Current	1+	$V_{IN} = 0V \text{ or } 5V$	$T_A = T_{MIN}$ to T_{MAX}	-5		+5	- μΑ
Negative Supply Current	- <u>;</u>		$T_A = +25^{\circ}C$	-1	-0.0001	+1	μΑ
Negative Supply Culterit	1-		$T_A = T_{MIN}$ to T_{MAX}	-5		+5	
Logic Supply Current	IL	All channels on or off,	$T_A = +25^{\circ}C$	-1	+0.001	+1	μΑ
Logic Supply Current	1 IL	$V_{IN} = 0V \text{ or } 5V$	$T_A = T_{MIN}$ to T_{MAX}		$V_{IN} = 0V \text{ or } 5V$ $T_A = T_{MIN} \text{ to } T_{MAX}$ -5		
Ground Current	Ignd	All channels on or off,	$T_A = +25^{\circ}C$	-1	-0.0001	+1	μA
	GND	$V_{IN} = 0V \text{ or } 5V$	$T_A = T_{MIN}$ to T_{MAX}	-5		+5	
DYNAMIC							
Turn-On Time	ton	V _S = 8V, Figure 2	$T_A = +25^{\circ}C$		300	400	ns
Turn-Off Time	toff	V _S = 8V, Figure 2	$T_A = +25^{\circ}C$		60	200	ns
Charge Injection (Note 3)	Q	$C_L = 1nF, V_{GEN} = 0,$ $R_{GEN} = 0\Omega$, Figure 3	T _A = +25°C		5	10	рС

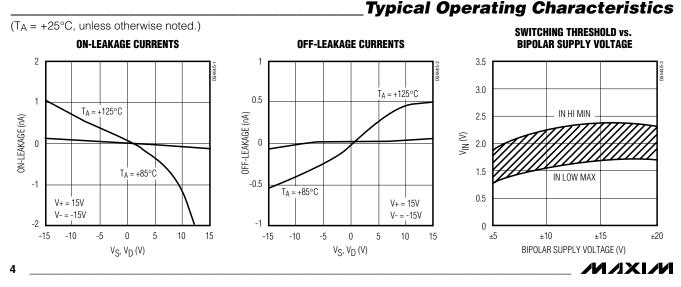
Note 2: Typical values are for **design aid only**, are not guaranteed, and are not subject to production testing. The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

Note 3: Guaranteed by design.

Note 4: On-resistance match between channels and flatness are guaranteed only with bipolar-supply operation. Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured at the extremes of the specified analog signal range.

Note 5: Leakage parameters $I_{S(OFF)}$, $I_{D(OFF)}$, $I_{D(ON)}$, and $I_{S(ON)}$ are 100% tested at the maximum rated hot temperature and guaranteed at +25°C. **Note 6:** Off-Isolation Rejection Ratio = 20log (V_D/V_S), V_D = output, V_S = input to off switch.

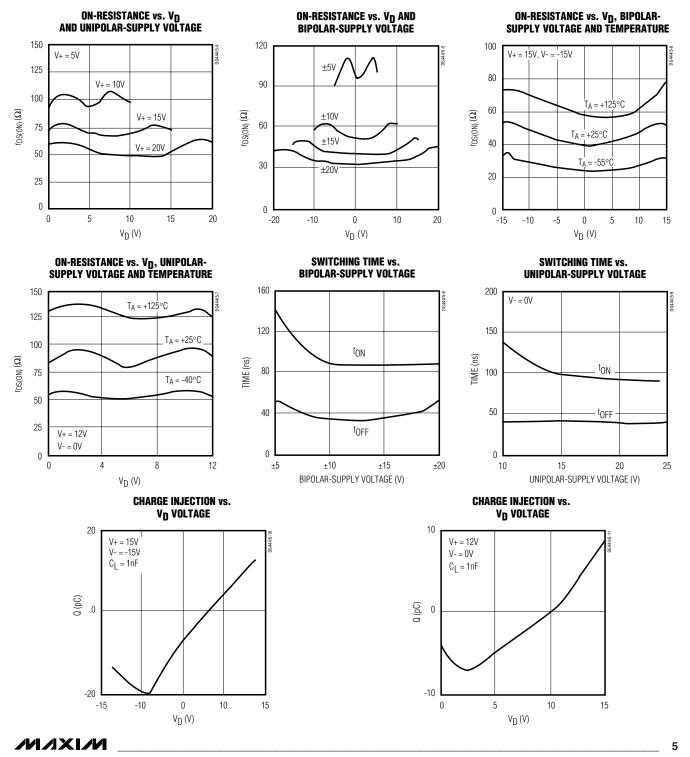
Note 7: Between any two switches.



_ _ _ _ _ _ _ _ _

Typical Operating Characteristics

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$



45	
4	DIP/SC
ğ	1, 16, 9,
4	2, 15, 10,
4	3, 14, 11,
G 4	4
	5
-	12

PIN

Pin Description

FUNCTION

DIP/SO	THIN QFN	NAME	FUNCTION
1, 16, 9, 8	15, 14, 7, 6	IN1–IN4	Logic Control Inputs
2, 15, 10, 7	16, 13, 8, 5	D1–D4	Drain Outputs
3, 14, 11, 6	1, 12, 9 4	S1–S4	Source Outputs
4	2	V-	Negative-Supply Voltage Input
5	3	GND	Ground
12	10	VL	Logic-Supply Voltage Input
13	11	V+	Positive-Supply- Voltage Input—Connected to Substrate
_	EP	PAD	Exposed Pad Connect Pad to V+

NAME

Applications Information

General Operation

- Switches are open when power is off.
- IN, D, and S should not exceed V+ or V-, even with the power off.
- Switch leakage is from each analog switch terminal to V+ or V-, not to other switch terminals.

Operation with Supply Voltages Other than ±15V

Using supply voltages other than ±15V will reduce the analog signal range. The DG444/DG445 switches oper-

ate with $\pm 4.5V$ to $\pm 20V$ bipolar supplies or with a $\pm 10V$ to $\pm 30V$ single supply; connect V- to 0V when operating with a single supply. Also, all device types can operate with unbalanced supplies such as $\pm 24V$ and $\pm 5V$. V_L must be connected to $\pm 5V$ to be TTL compatible, or to V+ for CMOS-logic level inputs. The *Typical Operating Characteristics* graphs show typical on-resistance with $\pm 20V$, $\pm 15V$, $\pm 10V$, and $\pm 5V$ supplies. (Switching times increase by a factor of two or more for operation at $\pm 5V$.)

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, followed by V_L, V-, and logic inputs. If power-supply sequencing is not possible, add two small, external signal diodes in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to 1V below V+ and 1V above V-, but low switch resistance and low leakage characteristics are unaffected. Device operation is unchanged, and the difference between V+ and Vshould not exceed +44V.

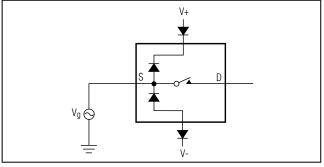
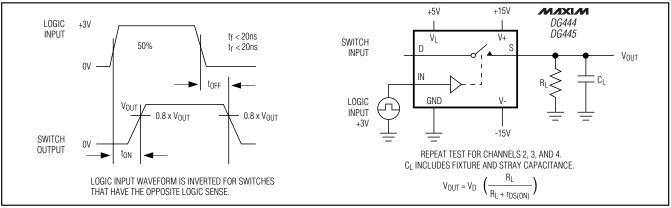
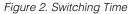


Figure 1. Overvoltage Protection Using External Blocking Diodes





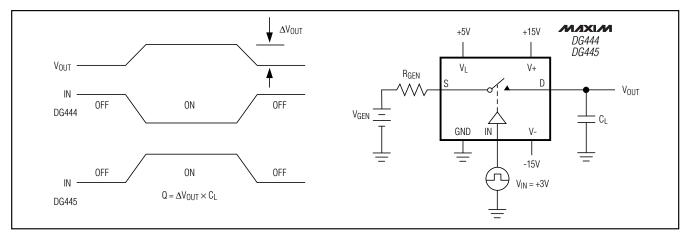


Figure 3. Charge Injection

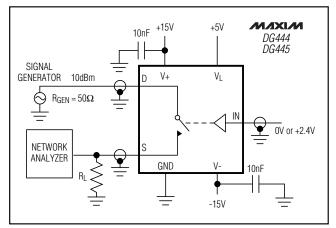


Figure 4. Off-Isolation Rejection Ratio

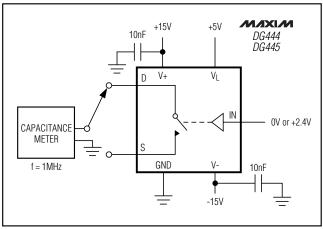


Figure 6. Source/Drain Off-Capacitance

MIXX/M

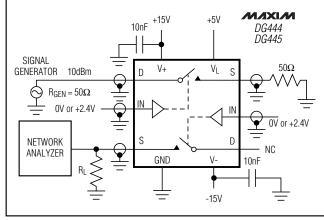


Figure 5. Crosstalk

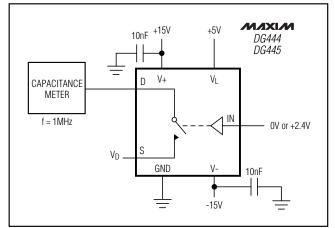
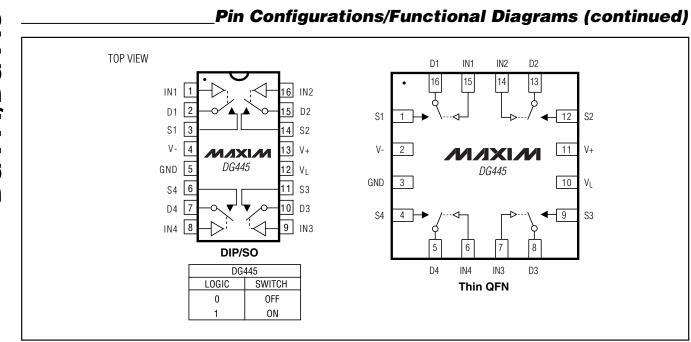


Figure 7. Source/Drain On-Capacitance



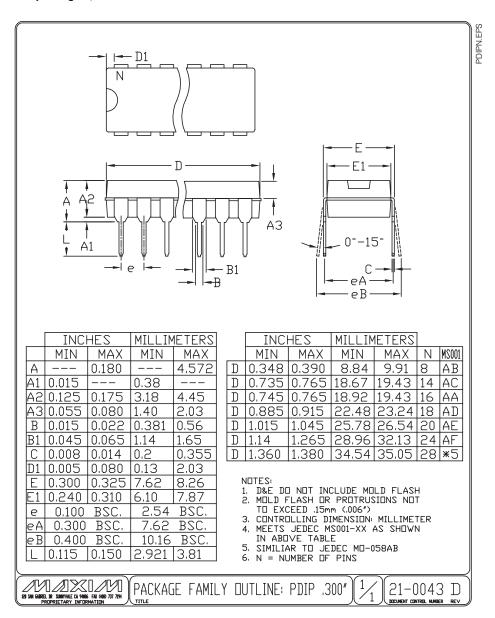
Ordering Information (continued)

PART	TEMP RANGE	PIN-PACKAGE
DG444ETE	-40°C to +85°C	16 Thin QFN (5mm x 5mm)
DG445 CJ	0°C to +70°C	16 Plastic DIP
DG445CY	0°C to +70°C	16 Narrow SO
DG445C/D	0°C to +70°C	Dice*
DG445DJ	-40°C to +85°C	16 Plastic DIP
DG445DY	-40°C to +85°C	16 Narrow SO
DG445ETE	-40°C to +85°C	16 Thin QFN (5mm x 5mm)

*Contact factory for dice specifications.

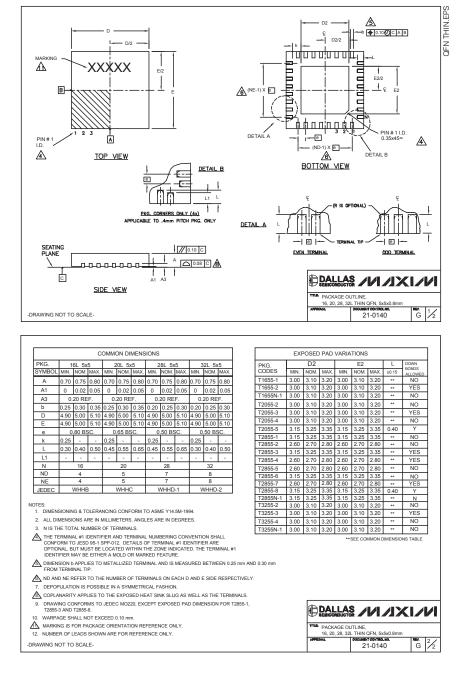
Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



_Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



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